

Hyper Mini TOPLED

Hyper-Bright LED

LB M673, LV M673, LT M673



Vorläufige Daten / Preliminary Data

Besondere Merkmale

- **Gehäusetyp:** weißes SMT Gehäuse
- **Besonderheit des Bauteils:** kleine Bauform für Anwendungen mit wenig Platzbedarf
- **Wellenlänge:** 470 nm (blau), 505 nm (verde), 528 nm (true green)
- **Abstrahlwinkel:** Lambertscher Strahler (120°)
- **Technologie:** InGaN
- **optischer Wirkungsgrad:** 2 lm/W (blau), 6 lm/W (verde), 8 lm/W (true green)
- **Gruppierungsparameter:** Lichtstärke, Wellenlänge
- **Verarbeitungsmethode:** für alle SMT-Bestücktechniken geeignet
- **Lötmethode:** IR Reflow Löten und Wellenlöten (TTW)
- **Vorbehandlung:** nach JEDEC Level 2
- **Gurtung:** 8 mm Gurt mit 3000/Rolle, ø180 mm oder 12000/Rolle, ø330 mm
- **ESD-Festigkeit:** ESD-sicher bis 2 kV nach EOS/ESD-5.1-1993

Anwendungen

- Informationsanzeigen im Außenbereich
- optischer Indikator
- Hinterleuchtung (LCD, Schalter, Tasten, Displays, Werbebeleuchtung, Allgemeinbeleuchtung)
- Innenbeleuchtung im Automobilbereich (z.B. Instrumentenbeleuchtung, u. ä.)
- Markierungsbeleuchtung (z.B. Stufen, Fluchtwiege, u.ä.)
- Signal- und Symbolleuchten

Features

- **package:** white SMT package
- **feature of the device:** small package for applications where small space is required
- **wavelength:** 470 nm (blue), 505 nm (green), 528 nm (true green)
- **viewing angle:** Lambertian Emitter (120°)
- **technology:** InGaN
- **optical efficiency:** 2 lm/W (blue), 6 lm/W (green), 8 lm/W (true green)
- **grouping parameter:** luminous intensity, wavelength
- **assembly methods:** suitable for all SMT assembly methods
- **soldering methods:** IR reflow soldering and TTW soldering
- **preconditioning:** acc. to JEDEC Level 2
- **taping:** 8 mm tape with 3000/reel, ø180 mm or 12000/reel, ø330 mm
- **ESD-withstand voltage:** up to 2 kV acc. to EOS/ESD-5.1-1993

Applications

- outdoor displays
- optical indicators
- backlighting (LCD, switches, keys, displays, illuminated advertising, general lighting)
- interior automotive lighting (e.g. dashboard backlighting, etc.)
- marker lights (e.g. steps, exit ways, etc.)
- signal and symbol luminaire

Typ Type	Emissionsfarbe Color of Emission	Farbe der Lichtaustrittsfläche Color of the Light Emitting Area	Lichtstärke Luminous Intensity $I_F = 20 \text{ mA}$ $I_V (\text{mcd})$	Lichtstrom Luminous Flux $I_F = 20 \text{ mA}$ $\Phi_V (\text{lm})$	Bestellnummer Ordering Code
LB M673-M1N1-1	blue	colorless clear	18.0 ... 35.5	77 (typ.)	Q62703-Q4840
LB M673-N1P2-1			28.0 ... 71.0	140 (typ.)	Q62703-Q4889
LV M673-P2Q2-1	verde	colorless clear	56 ... 112	240 (typ.)	Q62703-Q4847
LV M673-Q2S1-1			90 ... 224	440 (typ.)	Q62703-Q4893
LT M673-Q1R1-1	true green	colorless clear	71 ... 140	310 (typ.)	Q62703-Q4853
LT M673-R1S2-1			112 ... 280	560 (typ.)	Q62703-Q4897

Anm.: -1 gesamter Farbbereich, Lieferung in Einzelgruppen (siehe Seite 5)

Die Standardlieferform von Serientypen beinhaltet eine untere bzw. eine obere Familiengruppe, die aus nur 3 bzw. 4 Halbgruppen besteht. Einzelne Halbgruppen sind nicht erhältlich. In einer Verpackungseinheit / Gurt ist immer nur eine Halbgruppe enthalten.

Note: -1 Total color tolerance range, delivery in single groups (please see page 5)

The standard shipping format for serial types includes a lower or upper family group of 3 or 4 individual groups. Individual half groups are not available.

No packing unit / tape ever contains more than one luminous intensity half group.

Grenzwerte**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Werte Values		Einheit Unit
		LB	LV, LT	
Betriebstemperatur Operating temperature range	T_{op}	– 40 ... + 100		°C
Lagertemperatur Storage temperature range	T_{stg}	– 40 ... + 100		°C
Sperrschichttemperatur Junction temperature	T_j	+ 110	+ 125	°C
Durchlassstrom Forward current	I_F	20		mA
Stoßstrom Surge current $t \leq 10 \mu\text{s}, D = 0.005$	I_{FM}	200	250	A
Sperrspannung Reverse voltage	V_R	5		V
Leistungsaufnahme Power consumption $T_A \leq 25 \text{ }^\circ\text{C}$	P_{tot}	85		mW
Wärmewiderstand Thermal resistance Sperrschicht/Umgebung Junction/ambient	$R_{th JA}$	480		K/W
Sperrschicht/Löt pad Junction/solder point Montage auf PC-Board FR 4 (Padgröße $\geq 16 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 16 \text{ mm}^2$)	$R_{th JS}$	230		K/W

Kennwerte ($T_A = 25^\circ\text{C}$)

Characteristics

Bezeichnung Parameter	Symbol Symbol	Werte Values			Einheit Unit
		LB	LV	LT	
Wellenlänge des emittierten Lichtes Wavelength at peak emission $I_F = 20 \text{ mA}$	λ_{peak}	465	503	523	nm
Dominantwellenlänge ¹⁾ Dominant wavelength $I_F = 20 \text{ mA}$	λ_{dom}	470 ± 6	505 ± 7	528 ± 9	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 20 \text{ mA}$	$\Delta\lambda$	25	30	33	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) Viewing angle at 50 % I_V	2ϕ	120	120	120	Grad deg.
Durchlassspannung ²⁾ Forward voltage $I_F = 20 \text{ mA}$	V_F V_F	3.5 4.1	3.3 4.1	3.3 4.1	V V
Sperrstrom Reverse current $V_R = 5 \text{ V}$	I_R I_R	0.01 10	0.01 10	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} Temperature coefficient of λ_{peak} $I_F = 20 \text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{peak}}}$	0.04	0.03	0.04	nm/K
Temperaturkoeffizient von λ_{dom} Temperature coefficient of λ_{dom} $I_F = 20 \text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{dom}}}$	0.02	0.02	0.03	nm/K
Temperaturkoeffizient von V_F Temperature coefficient of V_F $I_F = 20 \text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	TC_V	-2.9	-3.2	-3.6	mV/K
Optischer Wirkungsgrad Optical efficiency $I_F = 20 \text{ mA}$	η_{opt}	2	6	8	lm/W

¹⁾ Wellenlängengruppen werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 1 \text{ nm}$ ermittelt.
Wavelength groups are tested at a current pulse duration of 25 ms and a tolerance of $\pm 1 \text{ nm}$.

²⁾ Spannungswerte werden mit einer Stromeinprägedauer von 1 ms und einer Genauigkeit von $\pm 0.1 \text{ V}$ ermittelt.
Voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1 \text{ V}$.

¹⁾ Wellenlängengruppen / Wavelength groups

Gruppe Group	blue		verde		true green		Einheit Unit
	min.	max.	min.	max.	min.	max.	
3	464	468	498	503	519	525	nm
4	468	472	503	507	525	531	nm
5	472	476	507	512	531	537	nm

Helligkeits-Gruppierungsschema
Luminous Intensity Groups

Lichtgruppe Luminous Intensity Group	Lichtstärke Luminous Intensity I_v (mcd)	Lichtstrom Luminous Flux Φ_v (mlm)
M1	18.0 ... 22.4	60 (typ.)
M2	22.4 ... 28.0	75 (typ.)
N1	28.0 ... 35.5	95 (typ.)
N2	35.5 ... 45.0	120 (typ.)
P1	45.0 ... 56.0	150 (typ.)
P2	56.0 ... 71.0	190 (typ.)
Q1	71.0 ... 90.0	240 (typ.)
Q2	90.0 ... 112.0	300 (typ.)
R1	112.0 ... 140.0	380 (typ.)
R2	140.0 ... 180.0	480 (typ.)
S1	180.0 ... 224.0	600 (typ.)
S2	224.0 ... 280.0	760 (typ.)

Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 11\%$ ermittelt.
 Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11\%$.

Gruppenbezeichnung auf Etikett
Group Name on Label

Beispiel: S2-3

Example: S2-3

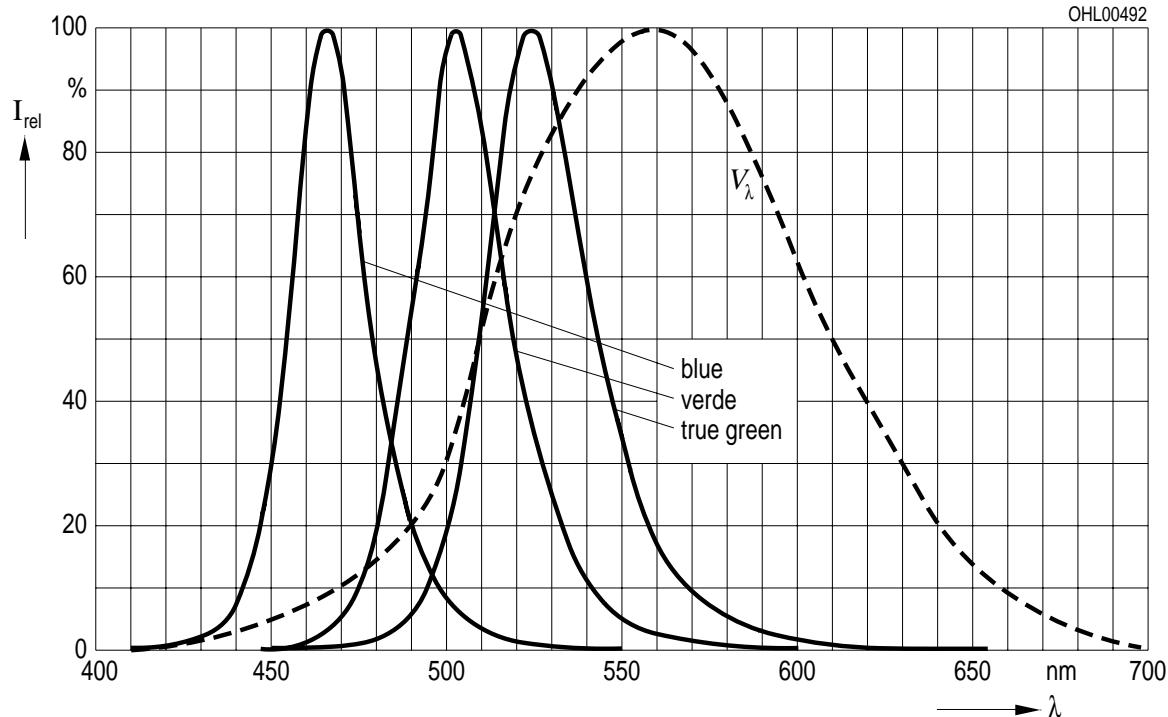
Lichtgruppe Luminous Intensity Group	Halbgruppe Half Group	Wellenlänge Wavelength
S	2	3

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ \text{C}$, $I_F = 20 \text{ mA}$

Relative Spectral Emission

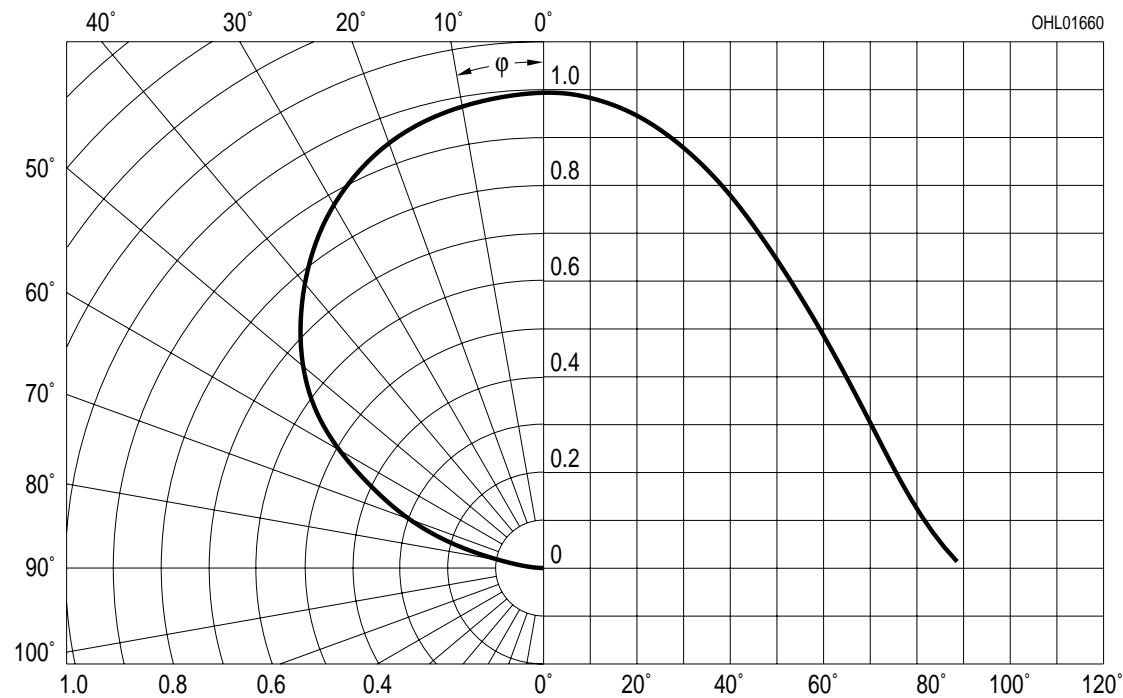
$V(\lambda) = \text{spektrale Augenempfindlichkeit}$

Standard eye response curve



Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

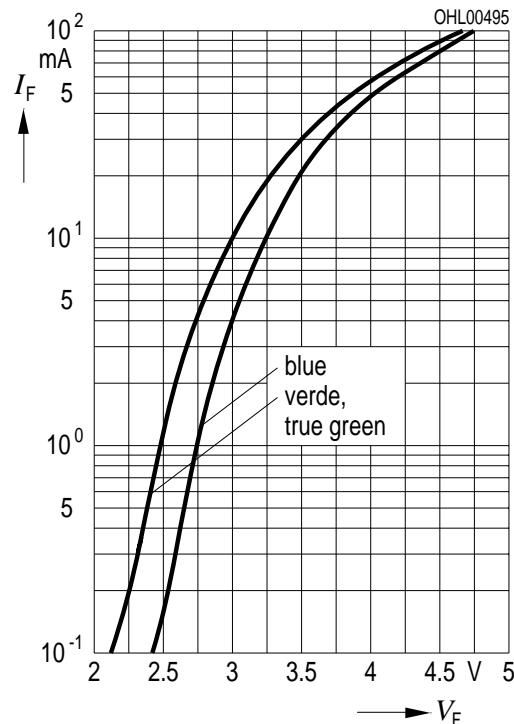
Radiation Characteristic



Durchlassstrom $I_F = f(V_F)$

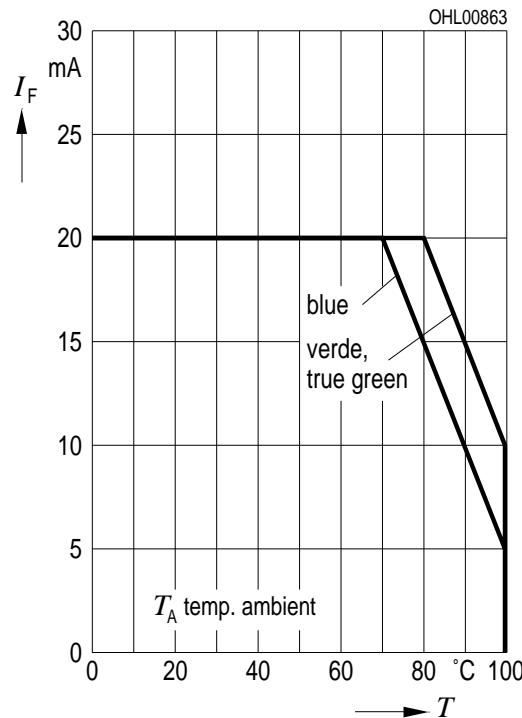
Forward Current

$T_A = 25^\circ\text{C}$



Maximal zulässiger Durchlassstrom $I_F = f(T)$

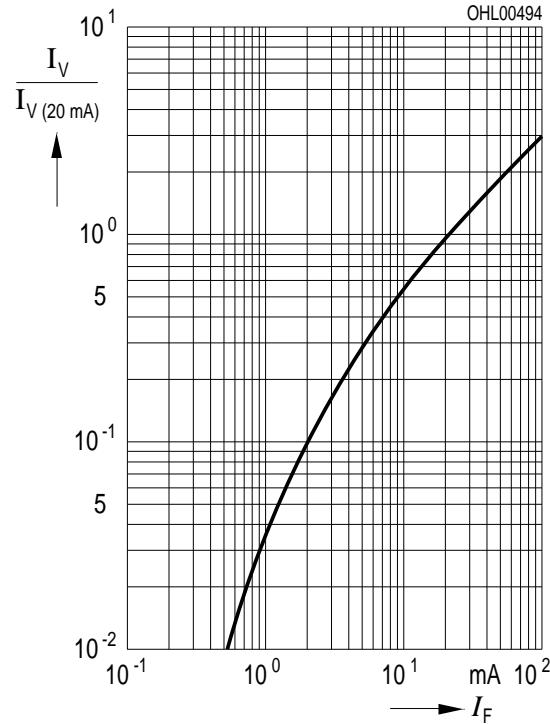
Max. Permissible Forward Current



Relative Lichtstärke $I_V/I_{V(20 \text{ mA})} = f(I_F)$

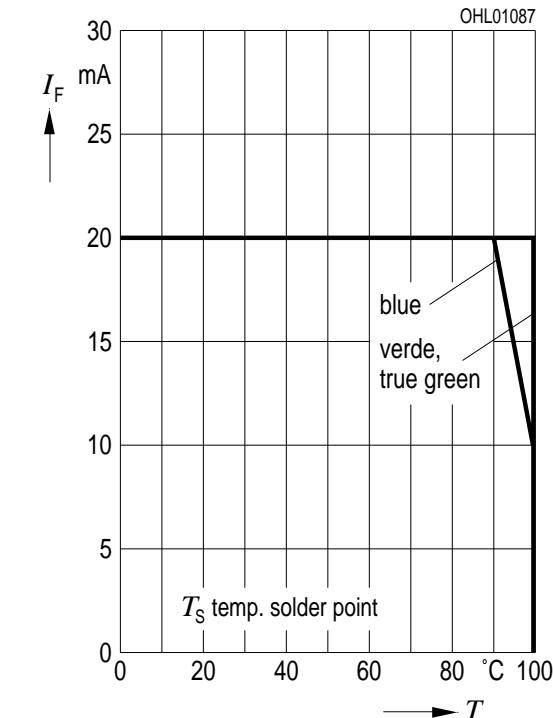
Relative Luminous Intensity

$T_A = 25^\circ\text{C}$



Maximal zulässiger Durchlassstrom $I_F = f(T)$

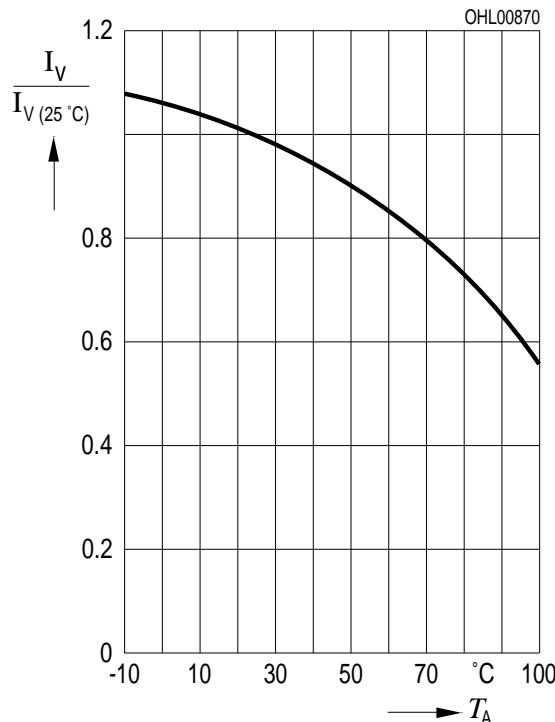
Max. Permissible Forward Current



Relative Lichtstärke $I_V/I_{V(25^\circ\text{C})} = f(T_A)$

Relative Luminous Intensity

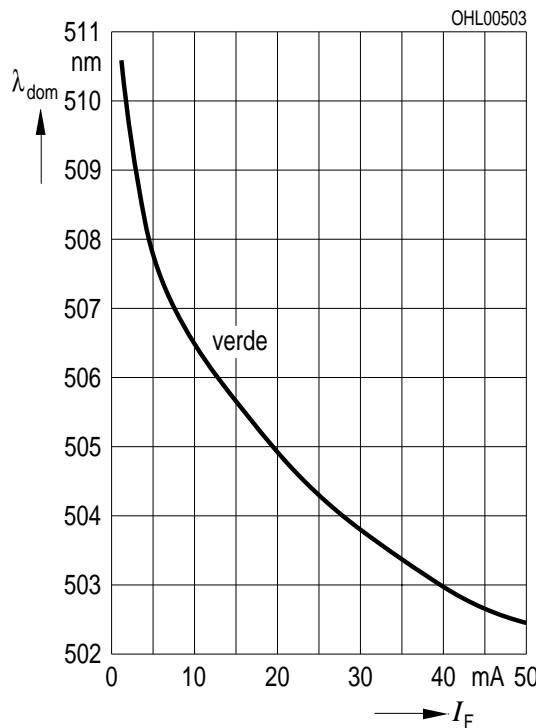
$I_F = 20 \text{ mA}$



Dominante Wellenlänge $\lambda_{\text{dom}} = f(I_F)$

Dominant Wavelength

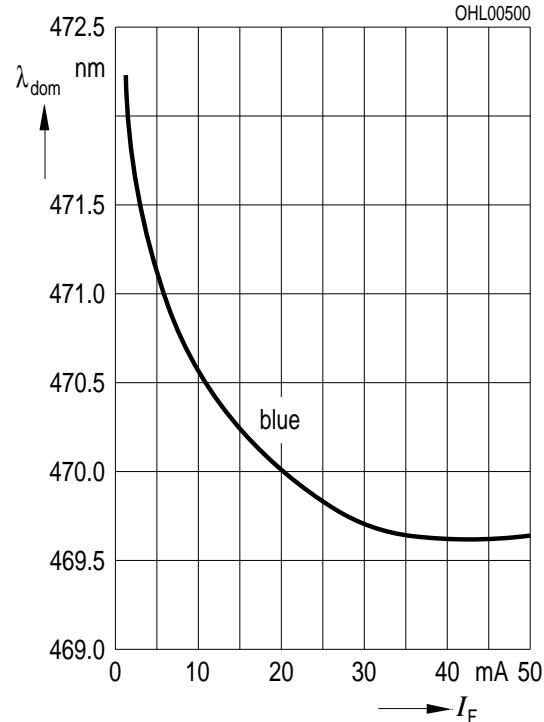
LV, $T_A = 25^\circ\text{C}$



Dominante Wellenlänge $\lambda_{\text{dom}} = f(I_F)$

Dominant Wavelength

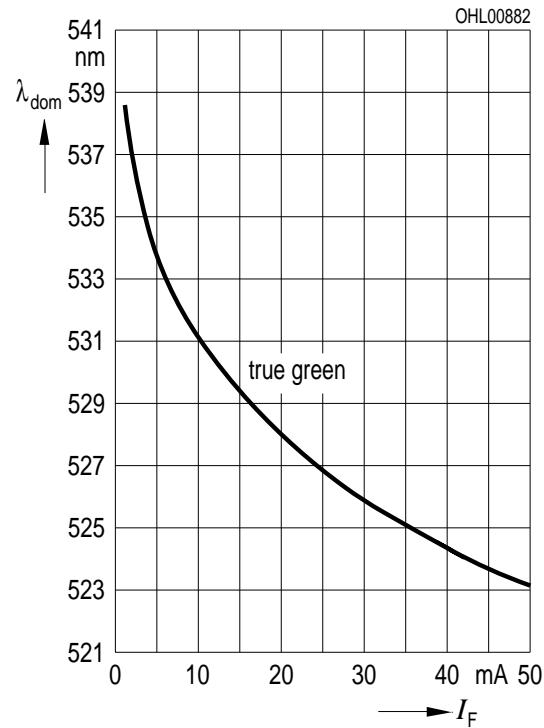
LB, $T_A = 25^\circ\text{C}$



Dominante Wellenlänge $\lambda_{\text{dom}} = f(I_F)$

Dominant Wavelength

LT, $T_A = 25^\circ\text{C}$

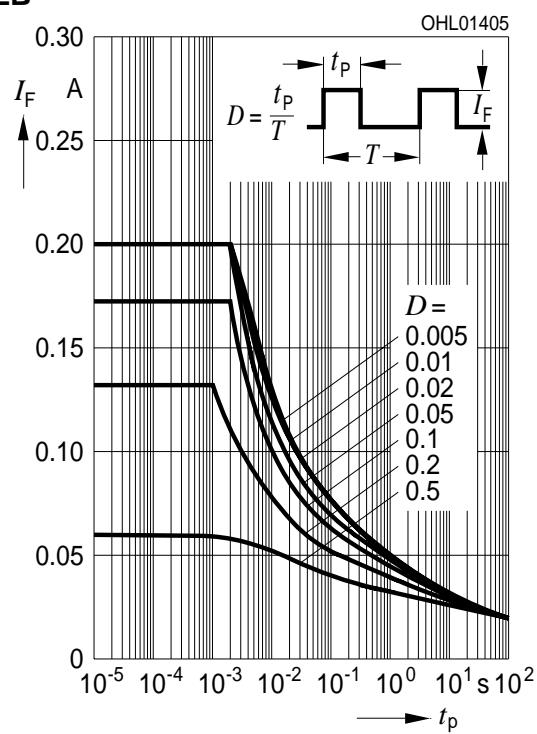


Zulässige Impulsbelastbarkeit $I_F = f(t_p)$

Permissible Pulse Handling Capability

Duty cycle D = parameter, $T_A = 25^\circ\text{C}$

LB

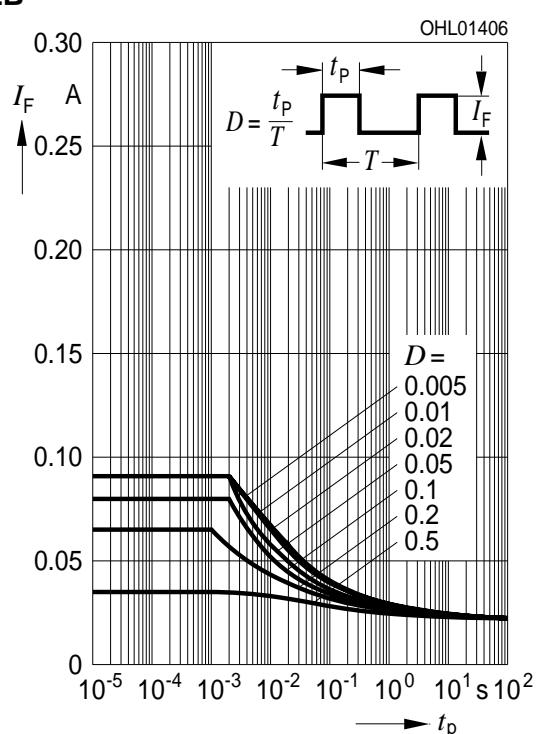


Zulässige Impulsbelastbarkeit $I_F = f(t_p)$

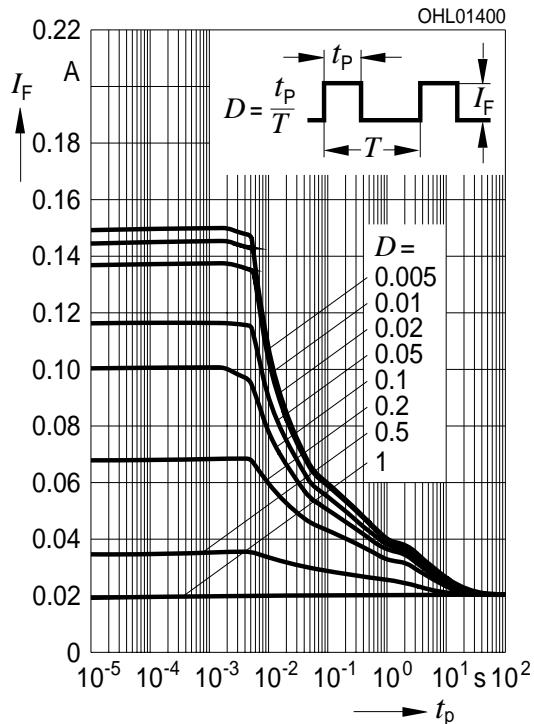
Permissible Pulse Handling Capability

Duty cycle D = parameter, $T_A = 85^\circ\text{C}$

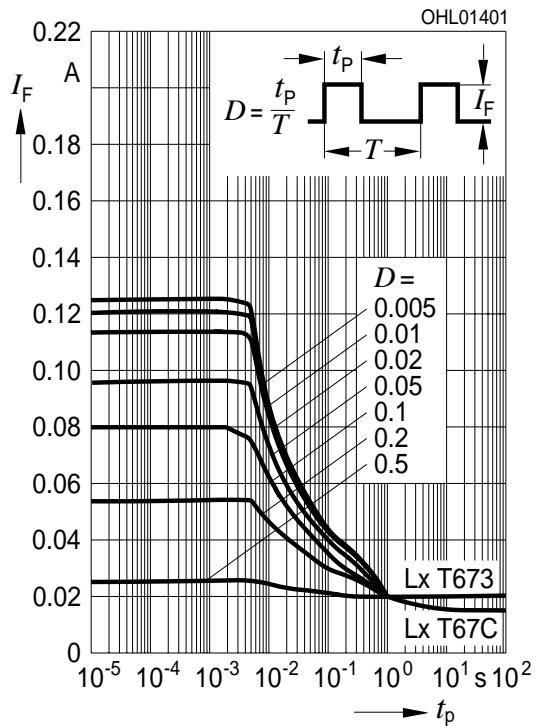
LB



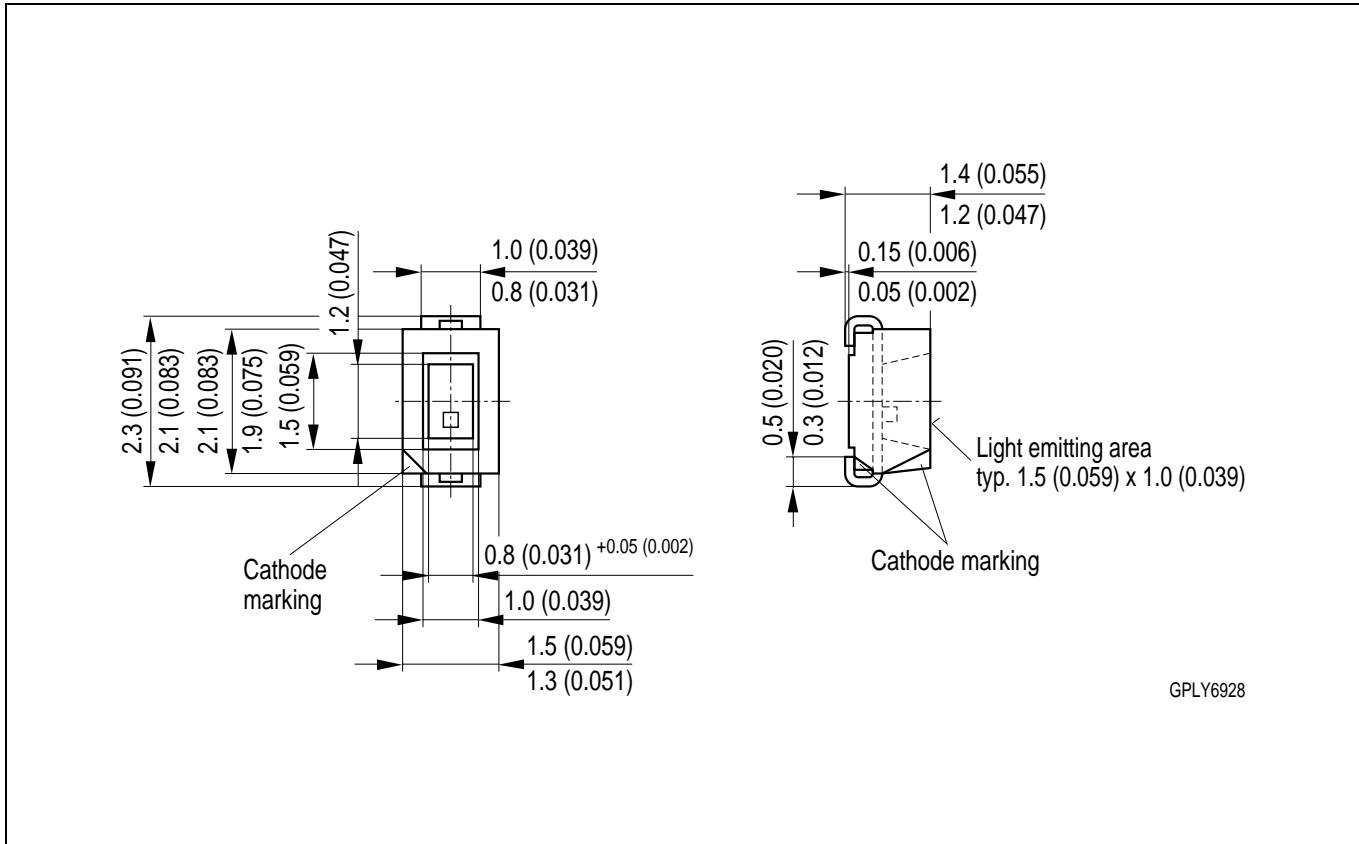
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle D = parameter, $T_A = 25^\circ\text{C}$
LV, LT



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle D = parameter, $T_A = 85^\circ\text{C}$
LV, LT



**Maßzeichnung
Package Outlines**



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

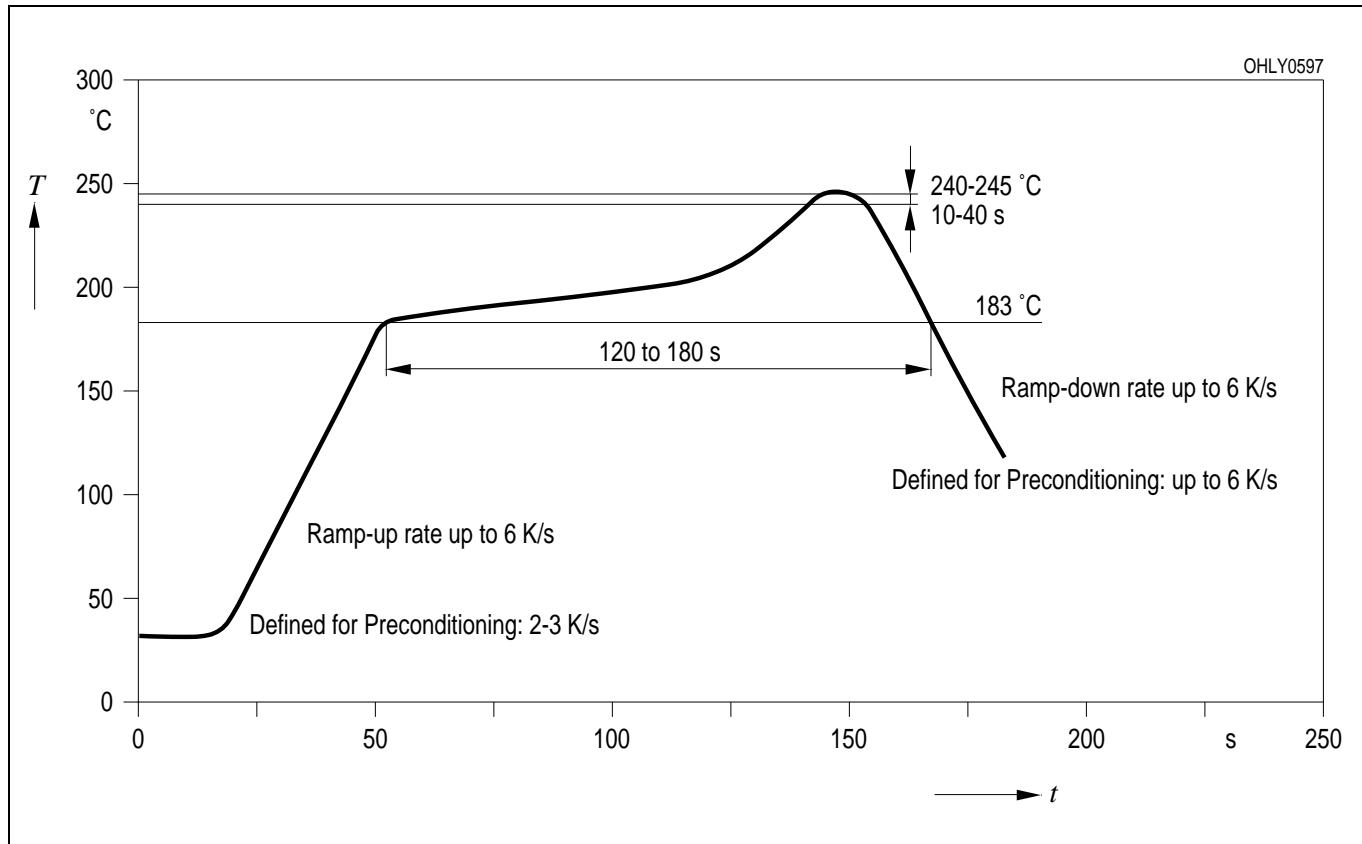
Kathodenkennung: abgeschrägte Ecke

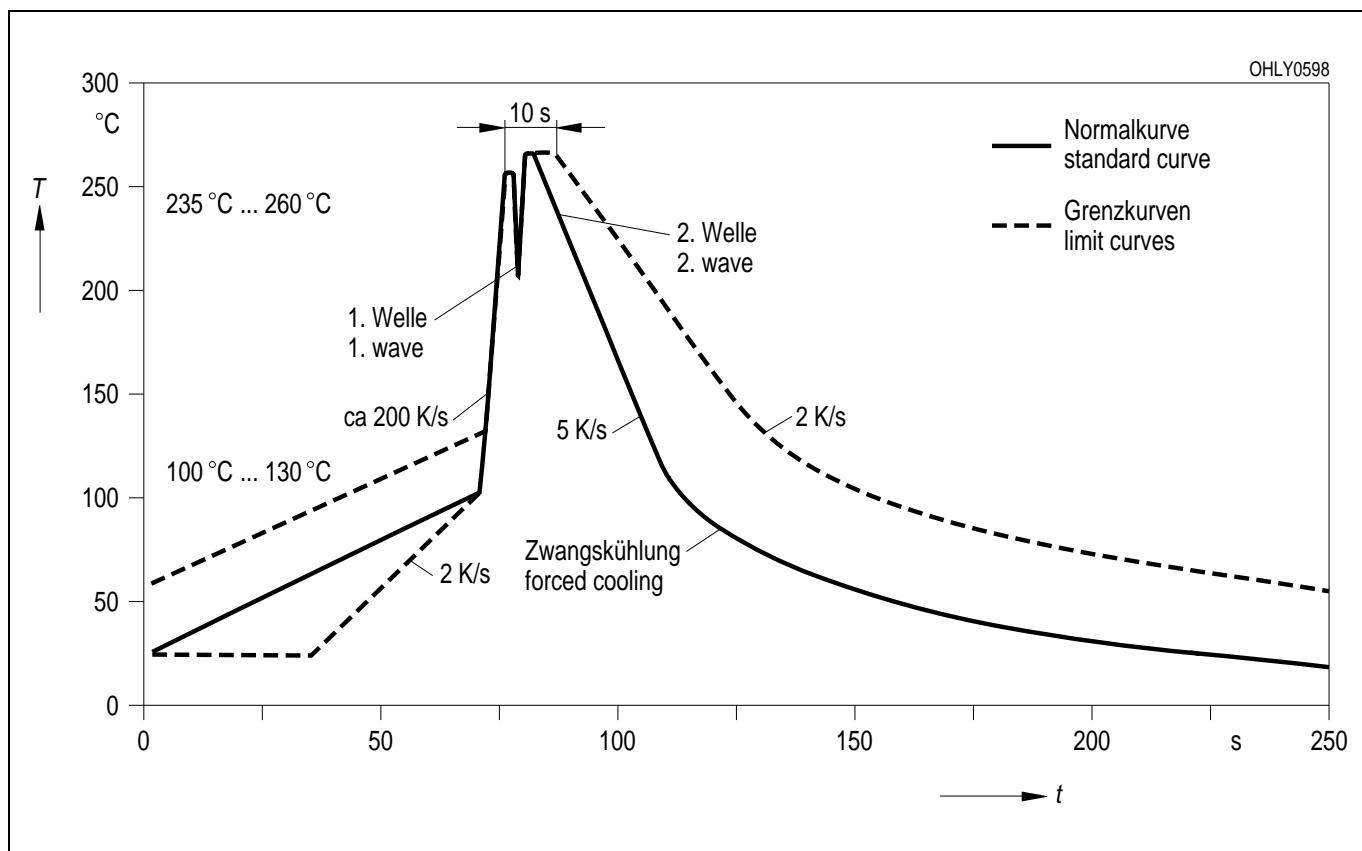
Cathode mark: bevelled edge

Gewicht / Approx. weight: 10 mg

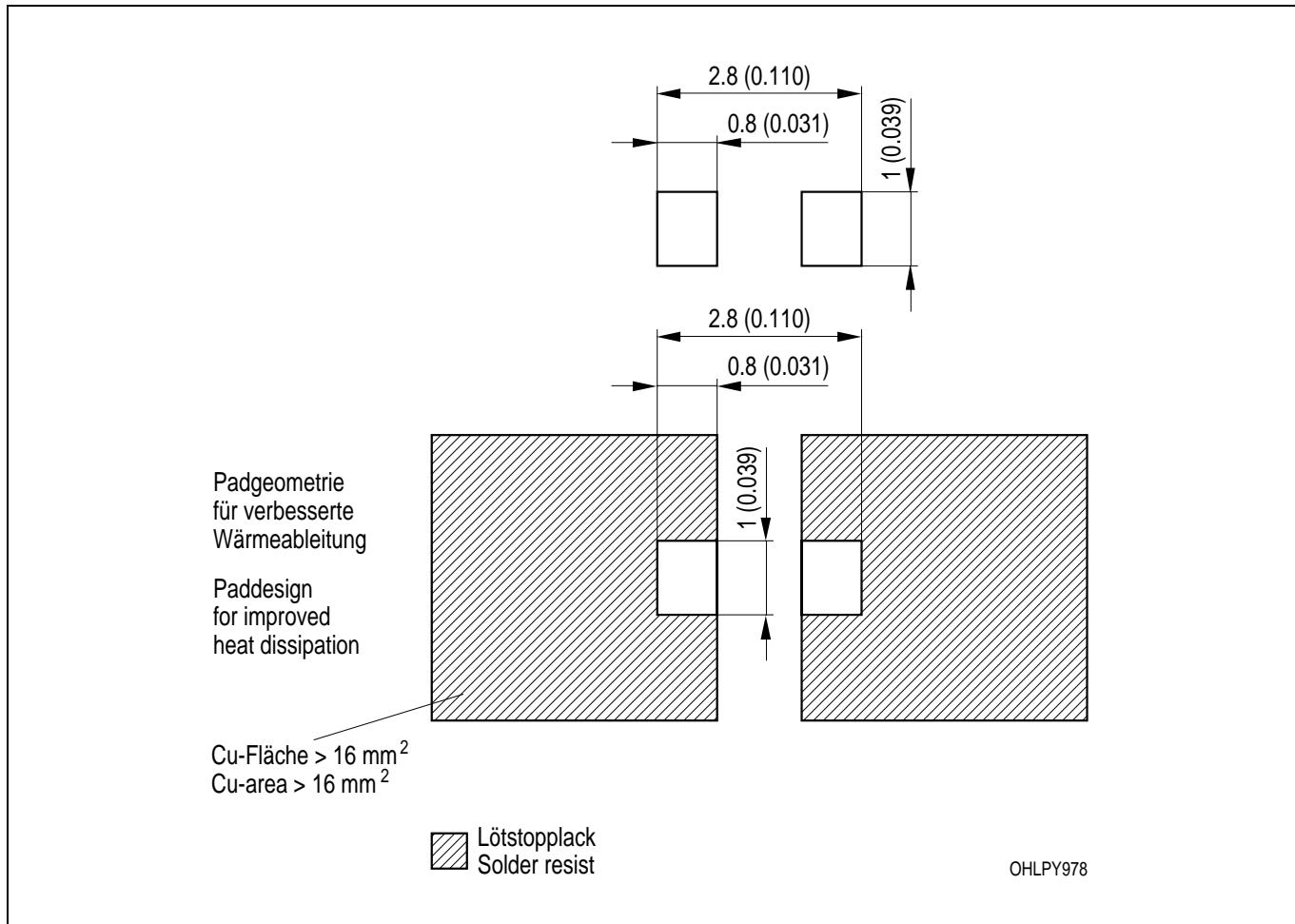
Lötbedingungen Vorbehandlung nach JEDEC Level 2
Soldering Conditions Preconditioning acc. to JEDEC Level 2

IR-Reflow Lötprofil (nach IPC 9501)
IR Reflow Soldering Profile (acc. to IPC 9501)



Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)

Empfohlenes Lötpaddesign IR Reflow Löten
Recommended Solder Pad IR Reflow Soldering



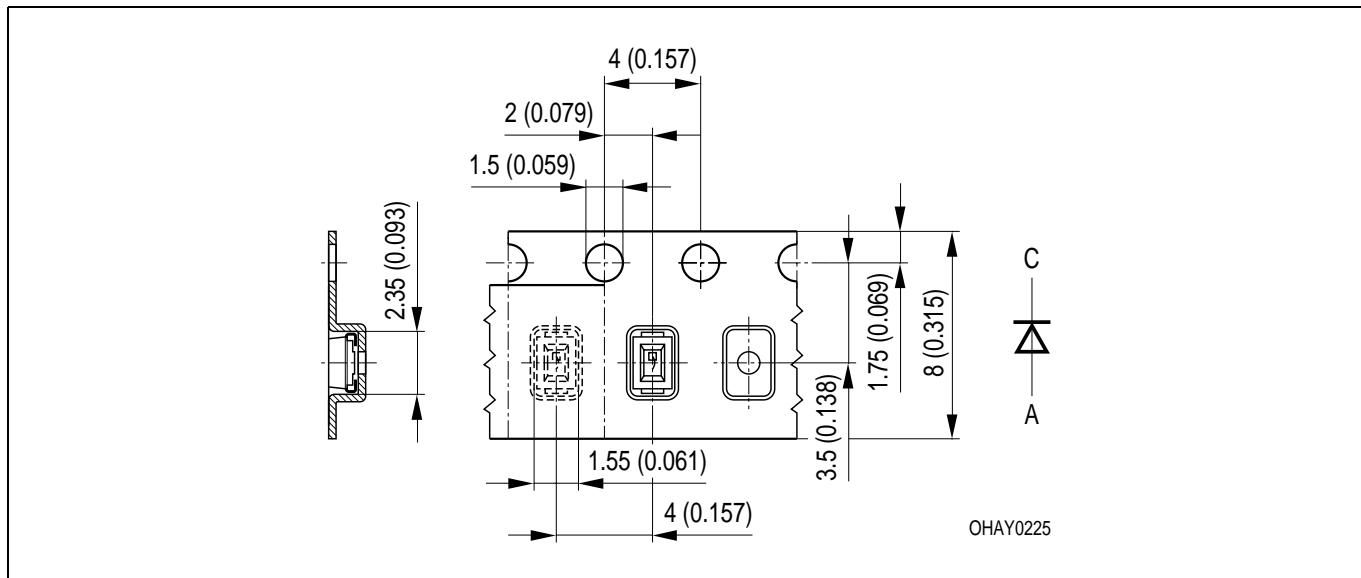
Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).
Gehäuse für Wellenlöten (TTW) geeignet / Package suitable for TTW-soldering

Gurtung / Polarität und Lage

Verpackungseinheit 3000/Rolle, ø180 mm
oder 12000/Rolle, ø330 mm

Method of Taping / Polarity and Orientation

Packing unit 3000/reel, ø180 mm
or 12000/reel, ø330 mm



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Revision History: 2001-05-03

Previous Version: 2001-05-03

Page	Subjects (major changes since last revision)

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If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components¹ may only be used in life-support devices or systems² with the express written approval of OSRAM OS.

¹ A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

² Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.